CSHD3-60

SURFACE MOUNT SILICON SCHOTTKY RECTIFIER 3 AMP, 60 VOLTS





www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CSHD3-60, silicon schottky rectifier is a high quality, well constructed, highly reliable component designed for use in all types of commercial, industrial, entertainment, computer and automotive applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T _C =25°C unless otherwise noted)	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	60	V
Average Rectified Forward Current (T _C =120°C)	IO	3.0	Α
Peak Forward Surge Current, tp=10ms	I _{FSM}	50	Α
Peak Repetitive Reverse Surge Current, tp=2.0µs	I _{RRM}	1.0	Α
Critical Rate of Rise of Reverse Voltage	dv/dt	10,000	V/µs
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	ΘJC	3.5	°C/W

$\textbf{ELECTRICAL CHARACTERISTICS:} \ (T_{\hbox{\scriptsize C}} = 25 ^{\circ} \hbox{\scriptsize C unless otherwise noted})$

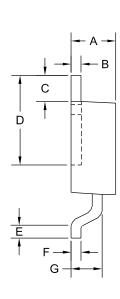
SYMBOL	TEST CONDITIONS	MAX	UNIT
I_{R}	V _R =60V	30	μΑ
I_{R}	V_R =60V, T_C =125°C	10	mA
VF	I _F =3.0A	0.75	V
V_{F}	I _F =3.0A, T _C =125°C	0.70	V

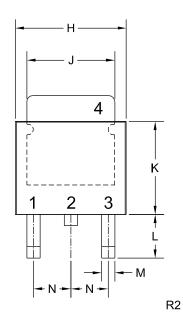
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DPAK RECTIFIER CASE - MECHANICAL OUTLINE



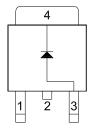


LEAD CODE:

- 1) No Connection
- 2) Cathode 3) Anode
- 4) Cathode

Pin 2 is Common to the Tab (4).

MARKING: FULL PART NUMBER



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.083	0.108	2.10	2.75			
В	0.016	0.024	0.40	0.60			
С	0.063		1.60				
D	0.203	0.219	5.15	5.55			
Е	0.039		1.00				
F	0.020		0.50				
G	0.051	0.071	1.30	1.80			
Н	0.248	0.268	6.30	6.80			
J	0.197	0.217	5.00	5.50			
K	0.209	0.224	5.30	5.70			
L	0.090	0.106	2.30	2.70			
М	0.012	0.031	0.30	0.80			
N	0.091		2.30				

DPAK RECTIFIER (REV: R2)

R7 (17-February 2010)